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Electrode Optimization Studies and Cathode Surface Chemistry:

Determination of Key Correlations between Surface Features and Electrochemical Performance

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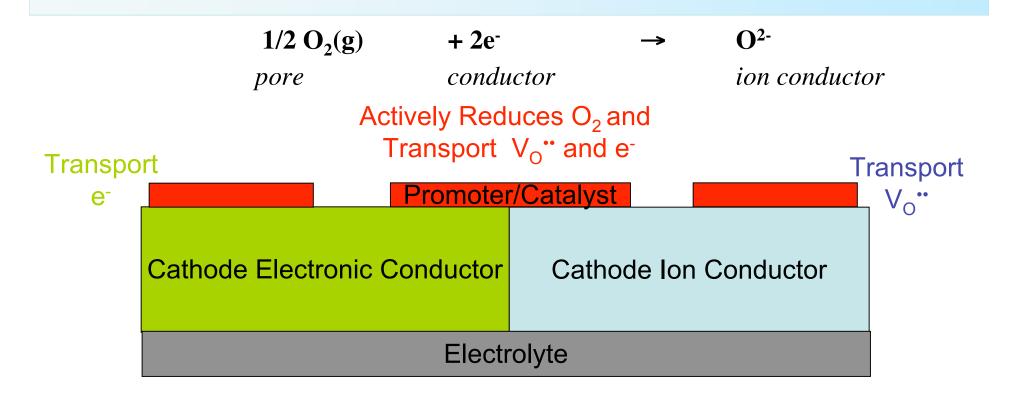
Outline for Cathode Surface Chemistry

Overview of Program (Started May 2007)
 Background
 Goals
 Approach
 Team

• Initial Thin Film Work at CMU
Growth Systems
Thin Film Characteristics
Demonstrations of Control

- Initial In-situ X-ray Characterization at ANL Environmental Chamber Initial Results
- Summary / Future

Ideal Cathode Materials



There is <u>no reason</u> to believe that the ideal backbone will have the ideal surface kinetics.

There <u>is</u> reason to believe that the <u>surface structure</u> of known backbones is <u>dynamic under load</u>.

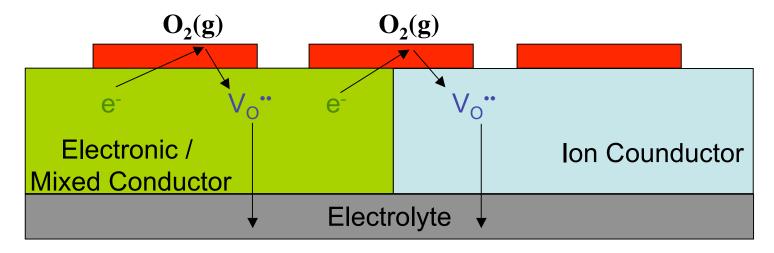
Can we understand / engineer highly-active and stable surfaces?

Ideal Surface Active Cathode Materials

Dynamic Surface / Promoter / Catalyst

- Actively Reduces O₂:
- Has high O₂ catalyst site density:
- Has sufficient population of V_O**:
- Has low interfacial resistance:
- Has long term surface stability:
- Actively conducts V_O••, e⁻:

Overlays both electronic and ionic conductor



Experimental Philosophy / Goals

The basic lack of direct correlations between <u>surface/interface</u> chemistry/structure and performance hinders the design of optimized (active/stable) SOFC Cathodes.

- Probe the nature of atomic scale <u>surface chemistry</u> or <u>interface crystallography</u> <u>rather</u> than the device scale micro-structural perturbations.
- Determine <u>key correlations</u> between: solid state atomic, electronic, and chemical <u>structure</u> parameters and kinetic electrochemical (mass and charge transfer) <u>performance</u> parameters.
- Correlations will be used to develop and employ:

 a <u>high throughput chemical screening methodology</u> that
 does <u>not</u> require cell optimization and that
 <u>will</u> provide a sensitive measure of activity/stability in operational conditions.

Conceptual Sample

General Schematic

1 - 2 Atomic or Unit Cell Monolayers

≈ 20 - 50 Unit Cells of Epitaxial Perovskite

Macroscopic, Single Crystal Perovskite Substrate of specific orientation / termination

Example

SrMnO₃

(100)-terminated (La,Sr)MnO₃

(100)-terminated SrTiO₃

Concept

Gate

Reservoir

|Support /

Electrolyte

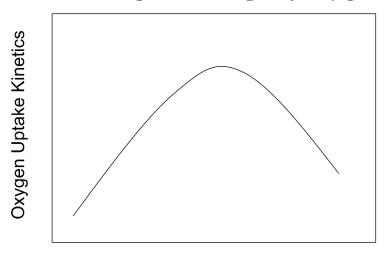
Reservoir Remains the Same while the Surface layer is Varied In this case:

LaMnO₃, SrMnO₃, SrO, MnO₂, or Metal (Pt, Ag, ...)

Surface Activity

Guiding ideas that will lead to generation of testable hypotheses:

- 1. A parameter can be identified that dictates the performance of perovskite cathodes
- 2. This parameter is surface sensitive and is related to: cation-gas bonding, vacancy population, electronic character, etc...
- 3. Noble metals can be used to change landscape of oxygen surface adsorption

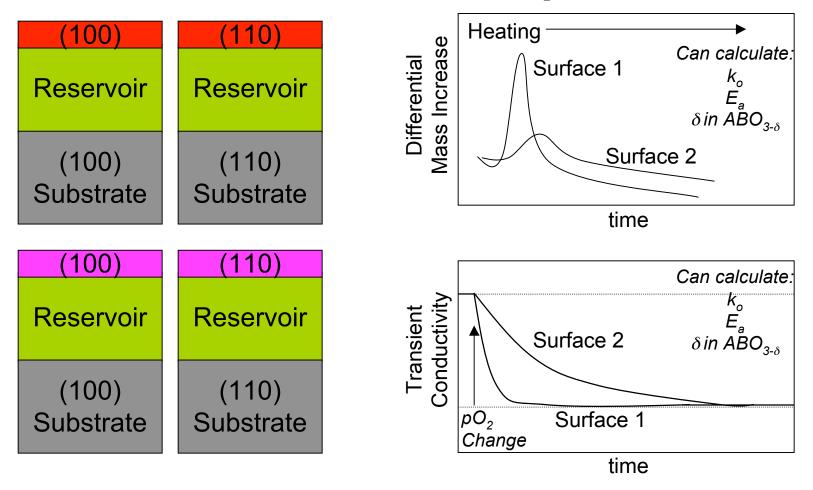


Heat of Oxide Formation of Outermost Layer
From literature or calculated

NEED NEW SAMPLE GEOMETRIES AND CHARACTERIZATION METHODS
REAL TIME, IN-SITU MEASUREMENTS OF SURFACE!

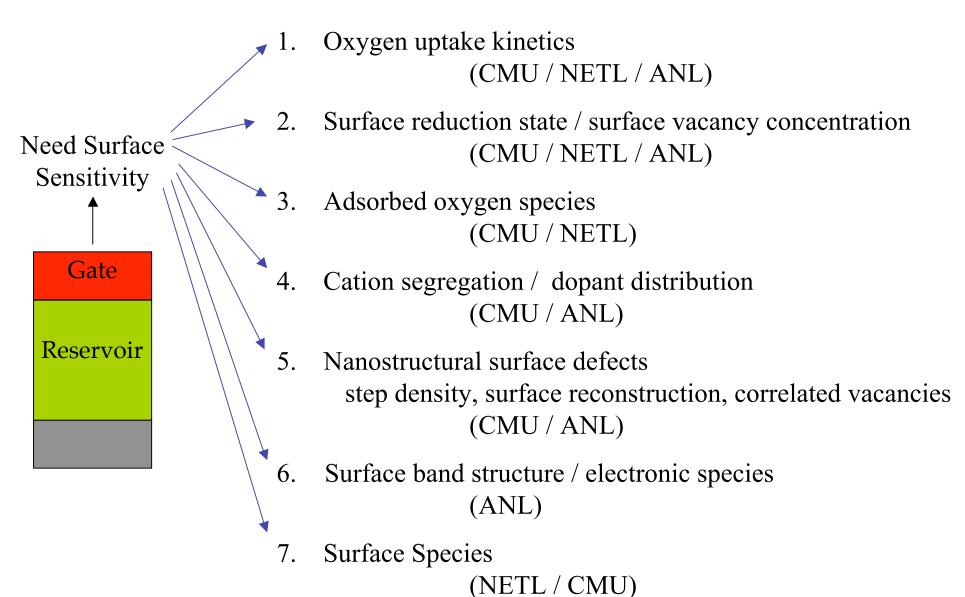
Schematic Approach

Probe the nature of atomic scale <u>surface chemistry</u> or <u>interface crystallography</u> <u>rather</u> than the device scale micro-structural perturbations.



Other techniques: Electrical and mass-uptake conductivity relaxation, IS ...

Experimental Values of Interest that are in Dynamic Equilibrium



Collaborators

Surface Engineering / Characterization / TEM

B. Kavaipatti, S. Wang, R. Petrova Carnegie Mellon

O. Maksimov, CMU/Penn State

<u>Detailed Structure and Surface Segregation vs</u> <u>Oxygen Activity</u>

J. Eastman, D. Fong, P. Fuoss APS, Argonne National Laboratories

Surface Stability / Interface Stability

L. Helmick, S. Seetharaman Carnegie Mellon

R. Gemman, C. Johnson National Energy Technology Laboratories

<u>Detailed Structure and Surface Segregation vs</u> <u>Electrochemical Activity</u>

K.-C. Chang, D. J. Myers, J. D. Carter, H. You APS, Argonne National Laboratories

B. Yildiz, MIT

Surface Chemistry

J. Kitchin Carnegie Mellon

C. Matranga National Energy Technology Laboratories

Electrochemical Activity and Cr-Poisoning

B. Ingram, T. Cruse, M. Krumpelt Argonne National Laboratories

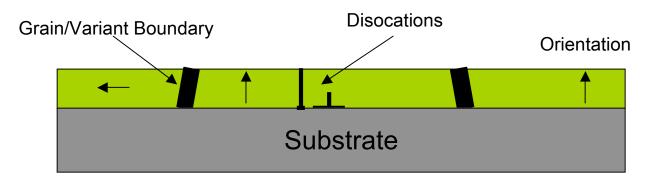
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Thin film approach



Characteristics of thin film growth that affect the oxygen uptake kinetics:

- Film thickness
- Film Morphology
- Orientation/Epitaxy
- Strain
- Dislocation networks
- Growth on electrolytic substrates
- Grain/Variant boundary
- Interdiffusion

Gate Materials:

- LaMnO₃
- SrMnO₃

Reservoir Materials:

- (*La*,*Sr*)*MnO*₃
- NdNiO₃

Substrate Materials

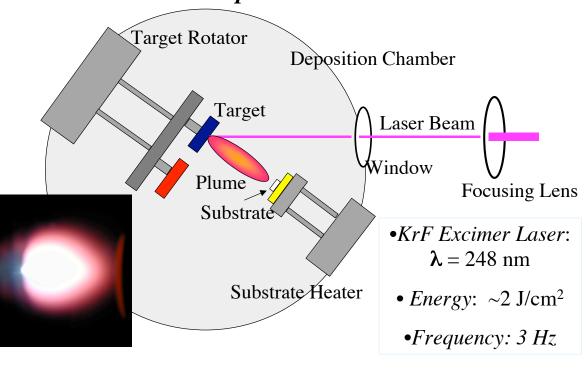
- SrTiO₃
- NdGaO3
- YSZ

Pulsed Laser Deposition Laser MBE / MBE

Advantages of PLD

- Targets made via standard methods.
- Stoichiometric transfer from target to film
- High-quality epitaxial films for complex oxides
- High-Quality Metal Films
- Simple, versatile, and relatively inexpensive
- House 6 targets at once

Pulsed Laser Deposition



Deposition Parameters

PRESSURE: 0.00001 - 0.2 Torr

TEMPERATURE: RT - 950 °C

FLUENCE: $1-8 \text{ J/cm}^2$

FREQUENCY: 1-10 Hz

COOLING: 0.00001- 300 Torr

Depositions: 1-4 hrs Max

3 - 4 deps / day

3 - 4 samples / dep



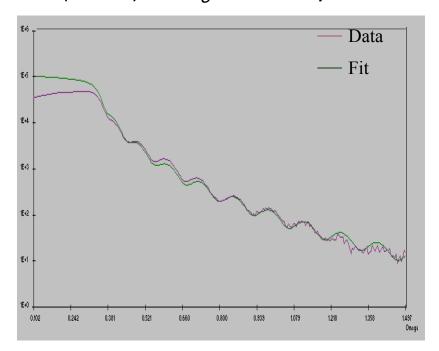


Growth rate / Surface Morphology

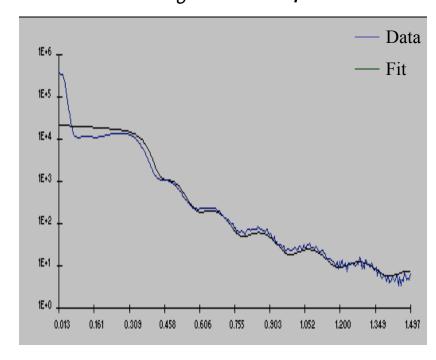
Oscillations in the X-ray reflectivity scan measure thickness

Determine growth rate of Reservoir and Gate

 $(La,Sr)MnO_3 - 0.11 \text{ Å/pulse}$



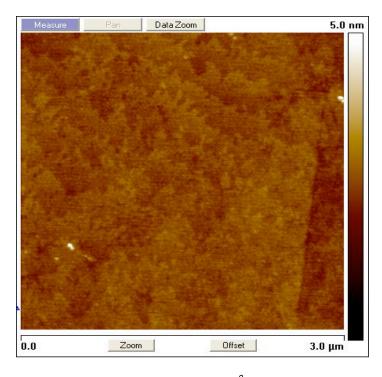
LaMnO₃ - 0.10 Å/pulse



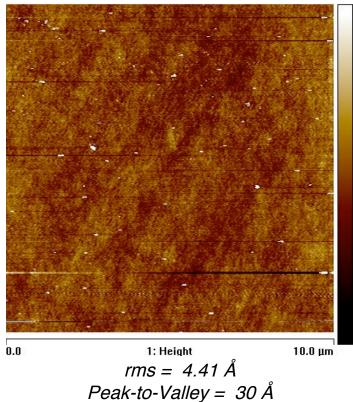
PLD Produces High Quality Surface Engineered Films with Controlled Thickness / Roughnes

Surface Morphology

$LaMnO_3$ and $(La,Sr)MnO_3$ films (~ 54 nm thick) with low roughnesses obtained on SrTiO₃(100) substrates



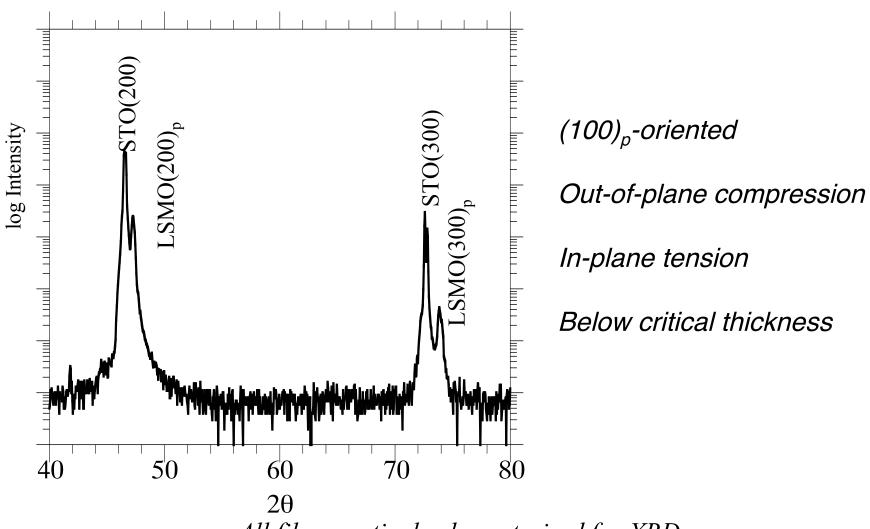
rms = 5.5 ÅPeak-to-Valley = 50 Å



PLD Produces High Quality Surface Engineered Films with Controlled Thickness / Roughnes

$(La,Sr)MnO_3$ thin films on $SrTiO_3(100)$

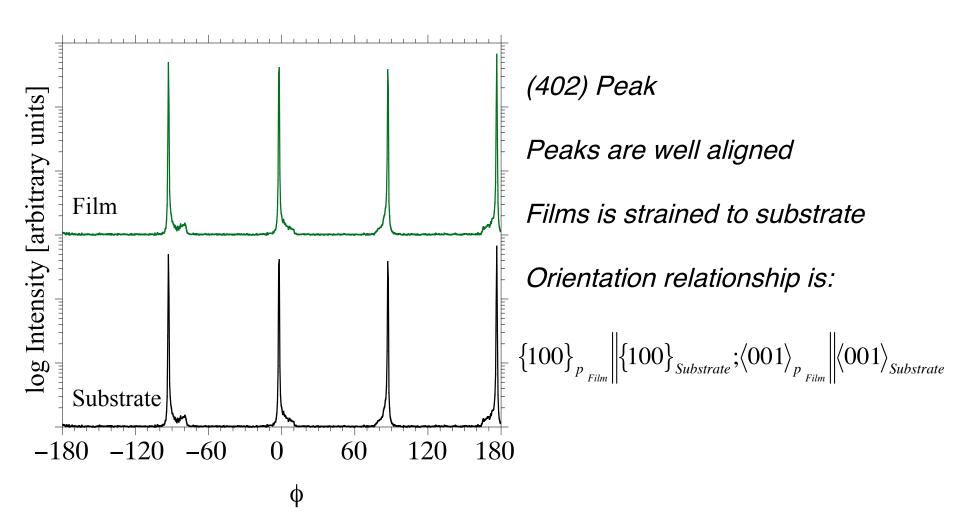
Standard X-ray Diffraction Scans of Films 54 nm thick



All films routinely characterized for XRD

In-plane orientation / Epitaxy

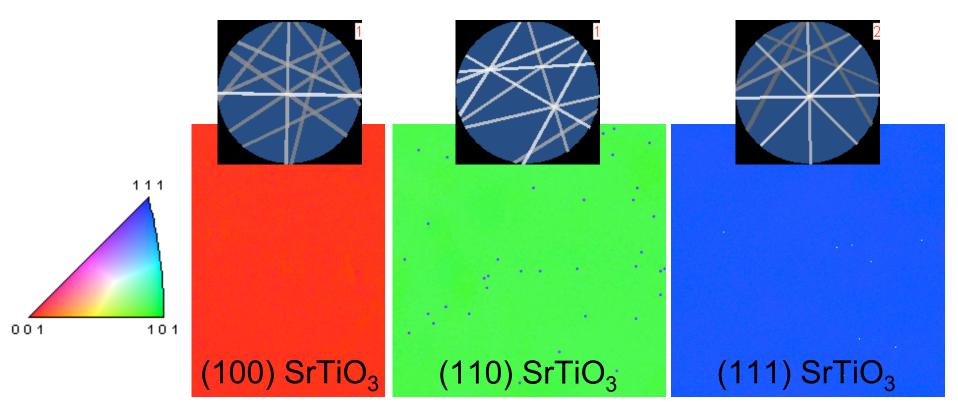
Phi Scan of in-plane X-ray Diffraction Scans of Films 54 nm thick



Standard Characterization Method to Ensure Quality Prior to Other Characterization₇

Epitaxy along various Orientations Orientation Mapping / Surface Sensitivity

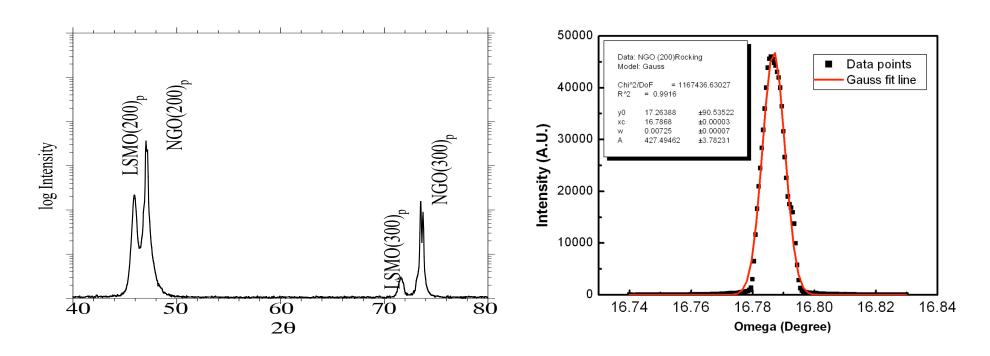
Electron Back-Scattered Diffraction used to Identify Local Orientations $La_{0.7}Sr_{0.3}MnO_3$ (50 nm) deposited on $SrTiO_3$ All scan areas > 20 x 20 micron²



All three low-index surfaces are obtained as epitaxial films

(La,Sr)MnO₃ thin films on High Quality Insulators

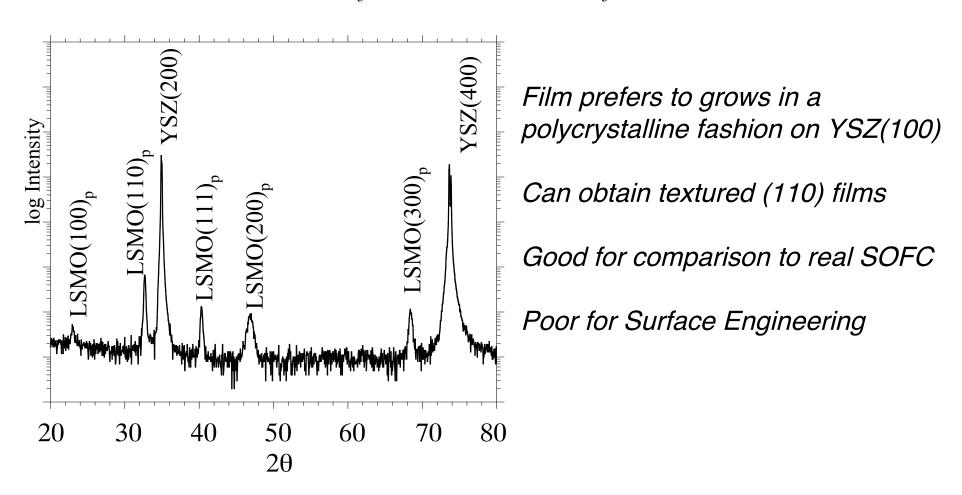
Control Strain State $La_{0.7}Sr_{0.3}MnO_3$ (54 nm) deposited on $NdGaO_3(100)_P$ Minimize Dislocations



Need Reasonable Perovskite Electrolyte(s) for Electrochemistry

$(La,Sr)MnO_3$ thin films on YSZ(100)

Perovskite / Fluorite Interface in ESSENTIAL in final ION TRANSFER

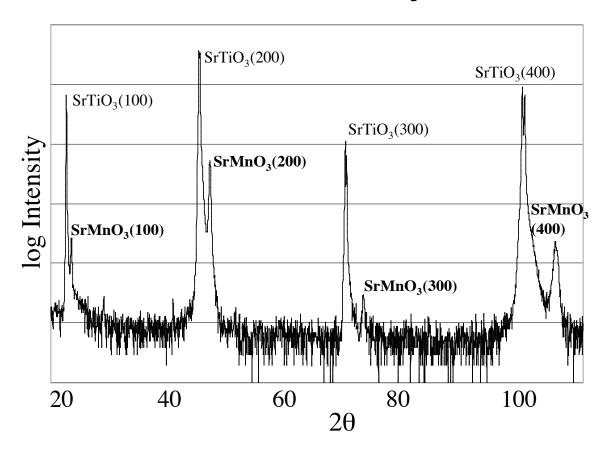


Will study both Fluorite and Perovskite Electrolytes using Electrochemical Methods Includes Synchrotron In-situ experiments

20

SrMnO₃ thin films on SrTiO₃(100) Alternate "native perovskite" gate for LSM

Highly-oriented (h00) perovskite-like films attained on the perovskite $SrTiO_3(100)$ substrates



Have made surface engineered samples with different gates: starting to measure *Intermixing?*

Artificial (LaMnO₃)_{15.5}(SrMnO₃)_{5.5} structures

Artificial Structures Stable

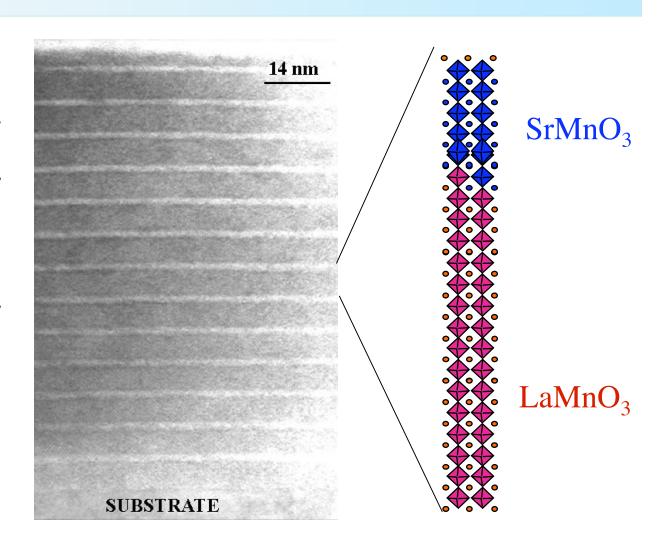
Mixing driving force small

Inner / Outer Layers Same

Surface can be engineered

Samples can be measured

Long term stability???



Samples are easy to grow once calibrated; several can be grown simulaneously

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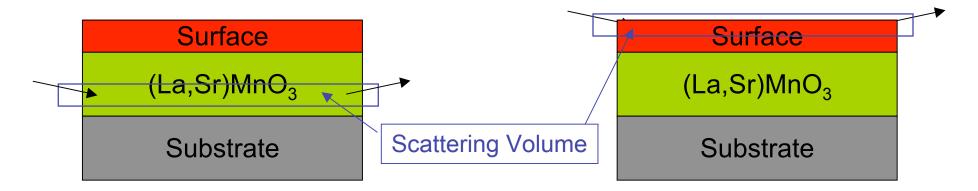
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Synchrotron Glancing Angle X-Ray

GOAL: Understand HOW (La,Sr)MnO₃ and (La,Sr)(Co,Fe)O₃ Behave

APPROACH: Use IDEAL Samples and Sensitive *In-Situ* Probe



- Environmetal Cell
- Good Samples
- Surface Morphology
- Grain/Variant boundary
- Segregation / Interdiffusion

- Beam Line / Time
- Structure
- Strain
- Temperature (Quenching?)
- Electrochemistry

Preliminary Investigation Using Synchrotron XRD

Environmental Chamber

Allows to Investigate
in appropriate cathode conditions

Temperature: RT - 800°C

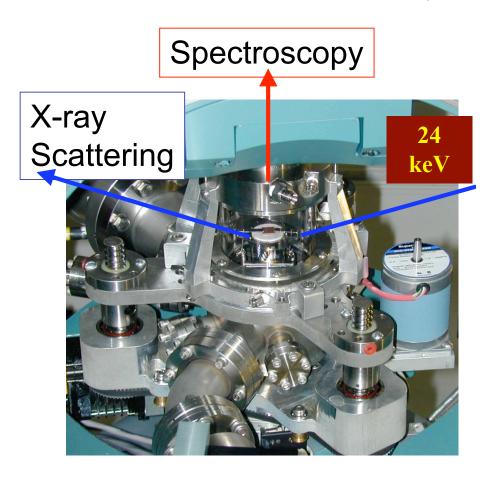
Pressure: 10^{-3} - $7x10^2$ Torr

Process Gas: O₂ - Argon

Flow Rate: 1 - 10³ sccm

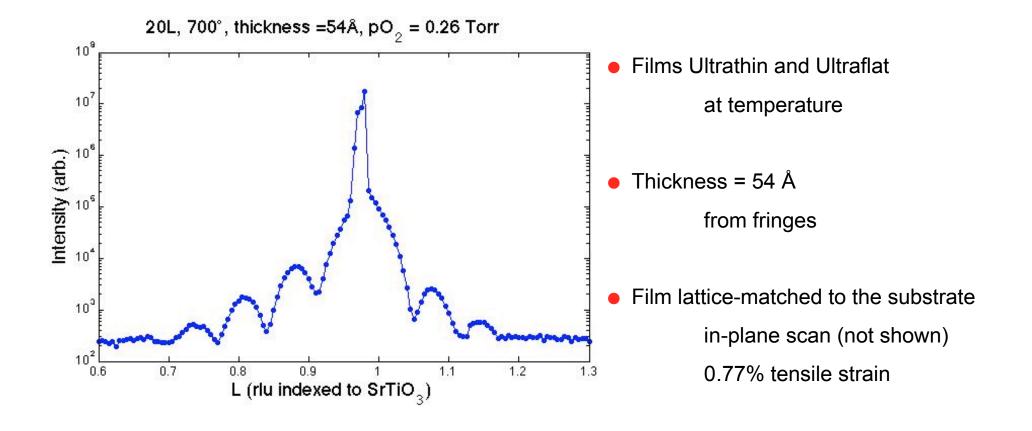
Ideal thin film samples:
atomically FLAT
no wafer curvature
Low dislocation content

Grazing Incidence X-ray
Provides Surface Sensitivity



$La_{0.7}Sr_{0.3}MnO_3$ on $SrTiO_3(100)$

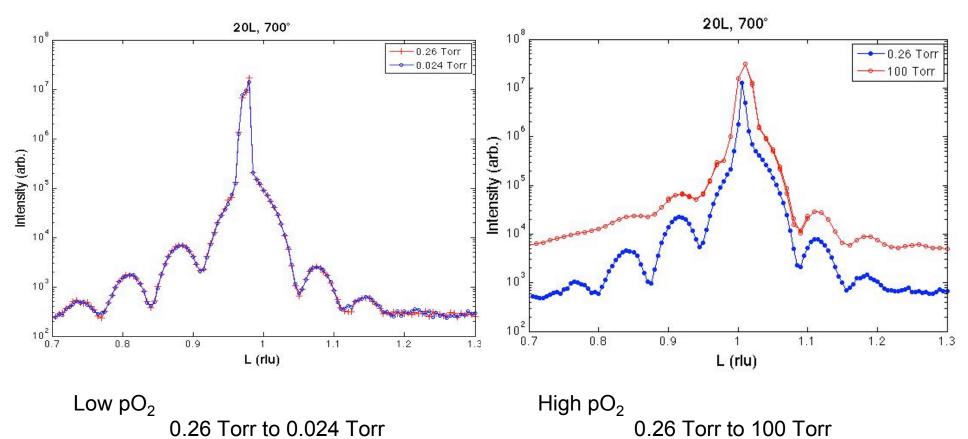
Glancing Angle Measurements on thick "Capping Layers" (14 Unit Cells)



PLD Produces
High Quality Surface Engineered Films that are Flat, Stable, and Measurable

Oxygen Pressure Effects In-situ Surface Morphology

Glancing Angle Measurements on Roughness of Thick Capping Layer

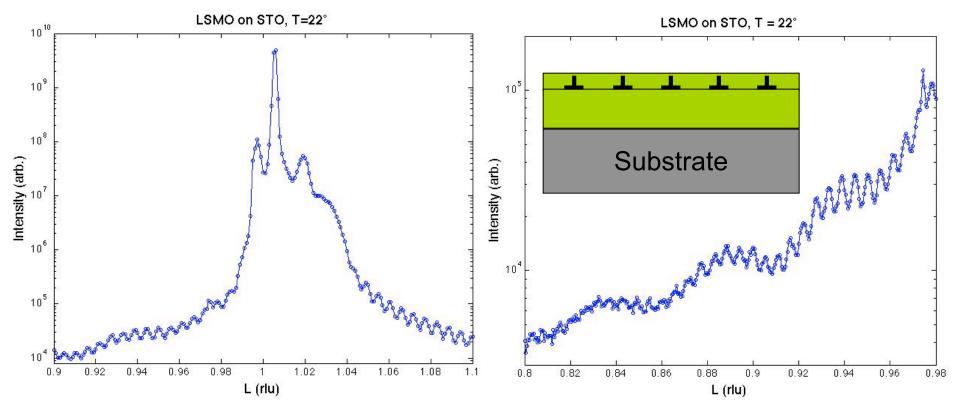


no measurable effect roughness increased

Real-time measure on affect of P/pO_2 on surface structure

Effects og Increasing Thickness

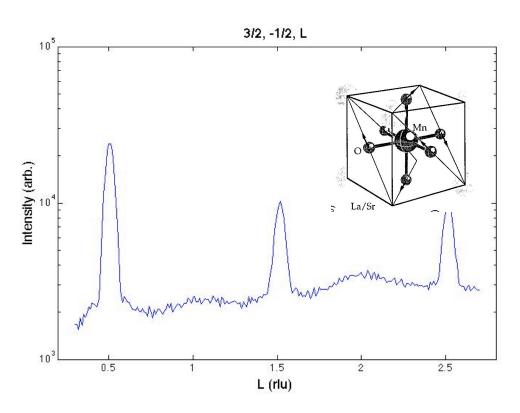
Glancing Angle Measurements on thin "Reservoirs" (200 Unit Cells)



- Thickness fringes with two characteristic lengths are observed (~68 nm and ~7.5 nm)
- Consistent with previous TEM observations of partially relaxed films
 - → Wiedenhurst et al. (J. Mag. Mag. Mater., **211**, 16, 2000) misfit dislocations localized to ~60 nm from the (La_{.7},Sr_{.3})MnO₃ / STO interface

Bulk Structure of Strained La_{0.7}Sr_{0.3}MnO₃

Scattering Measurements on thin "Reservoirs" (200 Unit Cells)

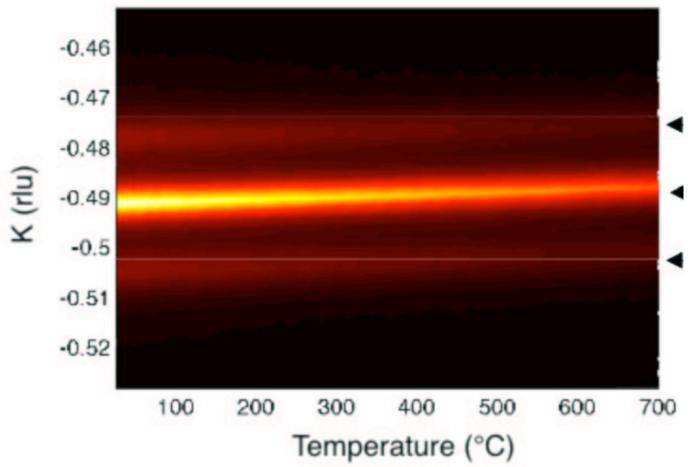


- Observe 1/2-order reflections;
 likely related to octahedral tilts
- Not typical for films at 700°C (not typical to observe this)
- Observed in polycrystalline LSMO;
 Martin et al. (PRB, 53,14285,1996)
 antiferrodistortive structure
- Need to Determine Origin

Bulk Reservoir Structure Determination In-situ

Temperature DependentStructure Investigations

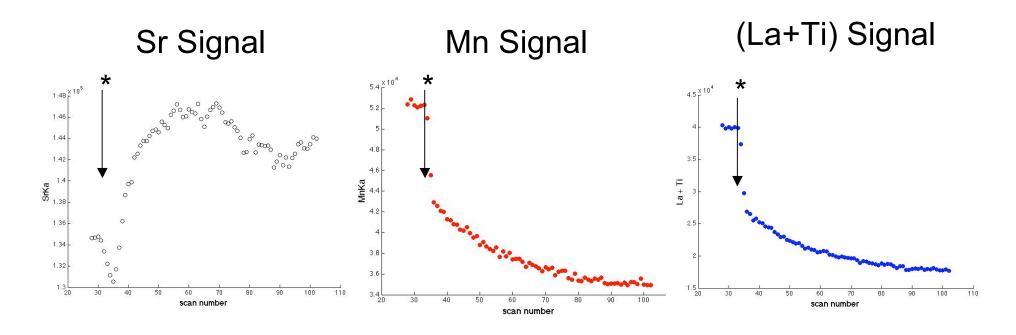
Scattering Measurements on thin "Reservoirs" (200 Unit Cells)



Superstructure Persists from Room-Temperature to 700°C

Surface Sensitive Fluorescence

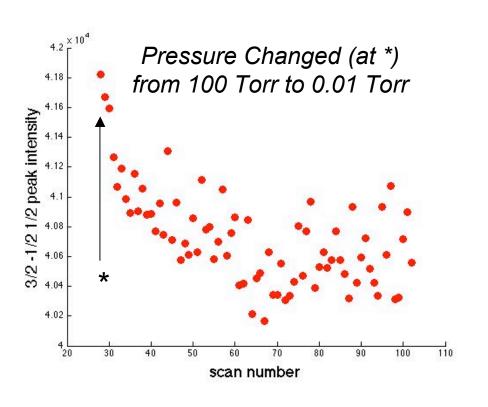
Pressure Changed (at *) from 100 Torr to 0.01 Torr



- 1. Careful analysis is required to correct for absorption: PRELIMINARY OBSERVATIONS
- 2. Sr-signal increases on decrease of pO_2 , while Mn and La(+Ti) decreases
- 3. Consistent with few literature reports that surface segregation occurs

Surface Structure

Surface Sensitive Scattering Measurements on thin "Reservoirs" (200 Unit Cells)



1/2-order reflections Persist

Only weak drop in intensity

Surface STRUCTURE weakly changed implies no clear phase separation

Need to combine fluoresence and XRD...

Both Structure and Composition of Surface Have been measured: being analyzed

Summary / Future Directions

- Effort focused on Thin Film / Engineered Surfaces

 CMU Generating Samples for Wide Ranging Efforts

 Characterize In-House Samples Prior to Sending

 Implement ECR / XPS / Auger In-House

 Develop / Implement High-T Crystal Microbalance

 Develop HIGH-THROUGHPUT Method to

 identify KEY CORRELATIONS
- Initial In-situ X-ray Characterization at ANL
 Environmental Chamber Analyze Results
 Investigate Surface Engineered Samples
 Use other Beams: Surface Electronic Structure / Electrochemical